

PMBD914

Single high-speed switching diode

Rev. 06 — 11 February 2009

Product data sheet

1. Product profile

1.1 General description

Single high-speed switching diode, fabricated in planar technology, and encapsulated in a small Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

| Type number ^[1] | Package | |
|----------------------------|---------|----------|
| | NXP | JEDEC |
| PMBD914 | SOT23 | TO-236AB |
| PMBD914/DG | | |

[1] /DG: halogen-free

1.2 Features

- High switching speed: $t_{rr} \leq 4$ ns
- Low leakage current
- Repetitive peak reverse voltage: $V_{RRM} \leq 100$ V
- Low capacitance: $C_d \leq 1.5$ pF
- Reverse voltage: $V_R \leq 100$ V
- Small SMD plastic package

1.3 Applications

- High-speed switching

1.4 Quick reference data

Table 2. Quick reference data

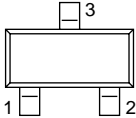
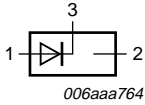
| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|----------|-----------------------|------------|------------------|-----|-----|------|
| I_F | forward current | | ^[1] - | - | 215 | mA |
| V_R | reverse voltage | | - | - | 100 | V |
| t_{rr} | reverse recovery time | | ^[2] - | - | 4 | ns |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] When switched from $I_F = 10$ mA to $I_R = 10$ mA; $R_L = 100$ Ω ; measured at $I_R = 1$ mA.

2. Pinning information

Table 3. Pinning

| Pin | Description | Simplified outline | Graphic symbol |
|-----|---------------|---|---|
| 1 | anode |  |  |
| 2 | not connected | | |
| 3 | cathode | | |

3. Ordering information

Table 4. Ordering information

| Type number ^[1] | Package | | |
|----------------------------|---------|--|---------|
| | Name | Description | Version |
| PMBD914 | - | plastic surface-mounted package; 3 leads | SOT23 |
| PMBD914/DG | | | |

[1] /DG: halogen-free

4. Marking

Table 5. Marking codes

| Type number | Marking code ^[1] |
|-------------|-----------------------------|
| PMBD914 | *5D |
| PMBD914/DG | YB* |

[1] * = -: made in Hong Kong
 * = p: made in Hong Kong
 * = t: made in Malaysia
 * = W: made in China

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------|-------------------------------------|-----------------|------------------|-----|------|
| V_{RRM} | repetitive peak reverse voltage | | - | 100 | V |
| V_R | reverse voltage | | - | 100 | V |
| I_F | forward current | | ^[1] - | 215 | mA |
| I_{FRM} | repetitive peak forward current | | - | 500 | mA |
| I_{FSM} | non-repetitive peak forward current | square wave | ^[2] | | |
| | | $t_p = 1 \mu s$ | - | 4 | A |
| | | $t_p = 1 ms$ | - | 1 | A |
| | | $t_p = 1 s$ | - | 0.5 | A |

Table 6. Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------|-------------------------|-----------------------------|--------|------|------|
| P_{tot} | total power dissipation | $T_{amb} \leq 25\text{ °C}$ | [1][3] | 250 | mW |
| T_j | junction temperature | | - | 150 | °C |
| T_{stg} | storage temperature | | -65 | +150 | °C |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] $T_j = 25\text{ °C}$ prior to surge.

[3] Soldering point of cathode tab.

6. Thermal characteristics

Table 7. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---------------|---|-------------|-----|-----|-----|------|
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | in free air | [1] | - | 500 | K/W |
| $R_{th(j-t)}$ | thermal resistance from junction to tie-point | | [2] | - | 330 | K/W |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

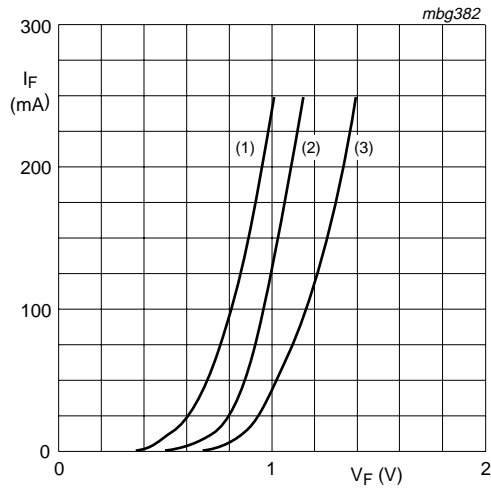
[2] Soldering point of cathode tab.

7. Characteristics

Table 8. Characteristics $T_{amb} = 25\text{ °C}$ unless otherwise specified.

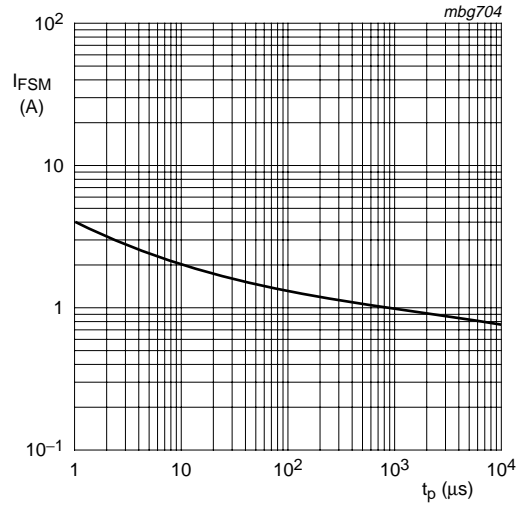
| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|----------|--------------------------|--|-----|-----|------|------|
| V_F | forward voltage | $I_F = 1\text{ mA}$ | - | - | 715 | mV |
| | | $I_F = 10\text{ mA}$ | - | - | 855 | mV |
| | | $I_F = 50\text{ mA}$ | - | - | 1 | V |
| | | $I_F = 150\text{ mA}$ | - | - | 1.25 | V |
| I_R | reverse current | $V_R = 25\text{ V}$ | - | - | 25 | nA |
| | | $V_R = 75\text{ V}$ | - | - | 1 | μA |
| | | $V_R = 25\text{ V}; T_j = 150\text{ °C}$ | - | - | 30 | μA |
| | | $V_R = 75\text{ V}; T_j = 150\text{ °C}$ | - | - | 50 | μA |
| C_d | diode capacitance | $f = 1\text{ MHz}; V_R = 0\text{ V}$ | - | - | 1.5 | pF |
| t_{rr} | reverse recovery time | | [1] | - | 4 | ns |
| V_{FR} | forward recovery voltage | | [2] | - | 1.75 | V |

[1] When switched from $I_F = 10\text{ mA}$ to $I_R = 10\text{ mA}$; $R_L = 100\text{ }\Omega$; measured at $I_R = 1\text{ mA}$.[2] When switched from $I_F = 10\text{ mA}$; $t_r = 20\text{ ns}$.



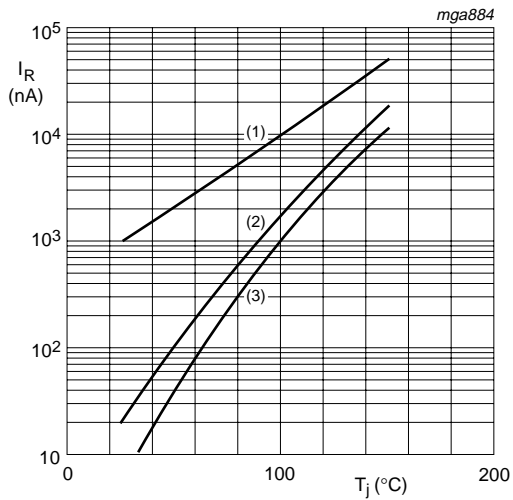
- (1) $T_{amb} = 150\text{ }^\circ\text{C}$; typical values
- (2) $T_{amb} = 25\text{ }^\circ\text{C}$; typical values
- (3) $T_{amb} = 25\text{ }^\circ\text{C}$; maximum values

Fig 1. Forward current as a function of forward voltage



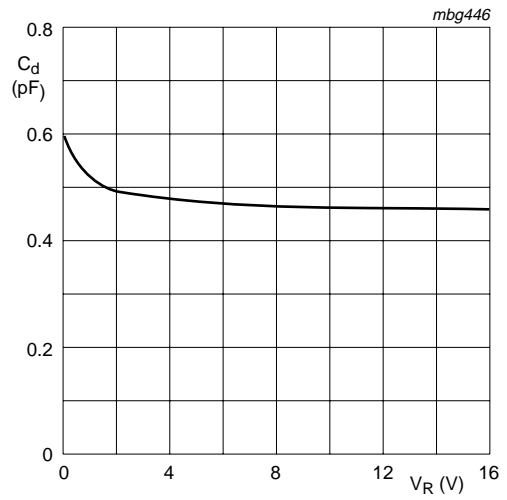
Based on square wave currents.
 $T_j = 25\text{ }^\circ\text{C}$; prior to surge

Fig 2. Non-repetitive peak forward current as a function of pulse duration; maximum values



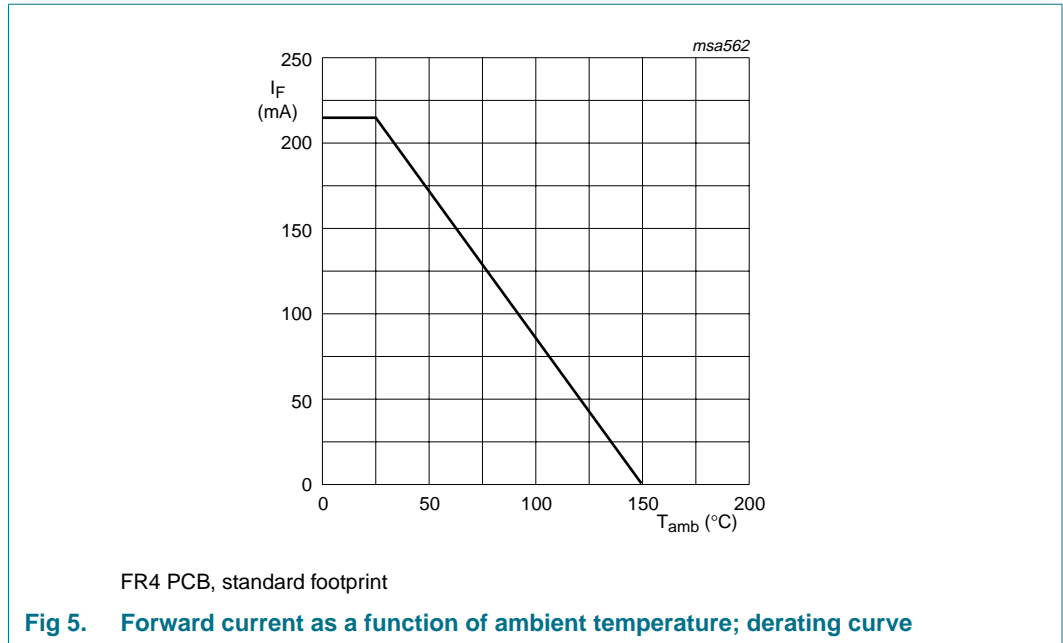
- (1) $V_R = 75\text{ V}$; maximum values
- (2) $V_R = 75\text{ V}$; typical values
- (3) $V_R = 25\text{ V}$; typical values

Fig 3. Reverse current as a function of junction temperature

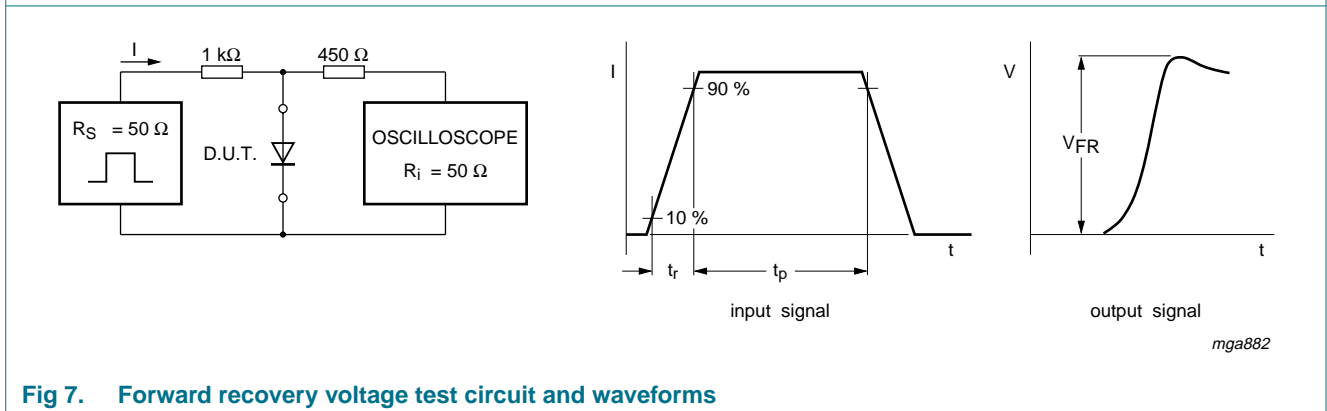
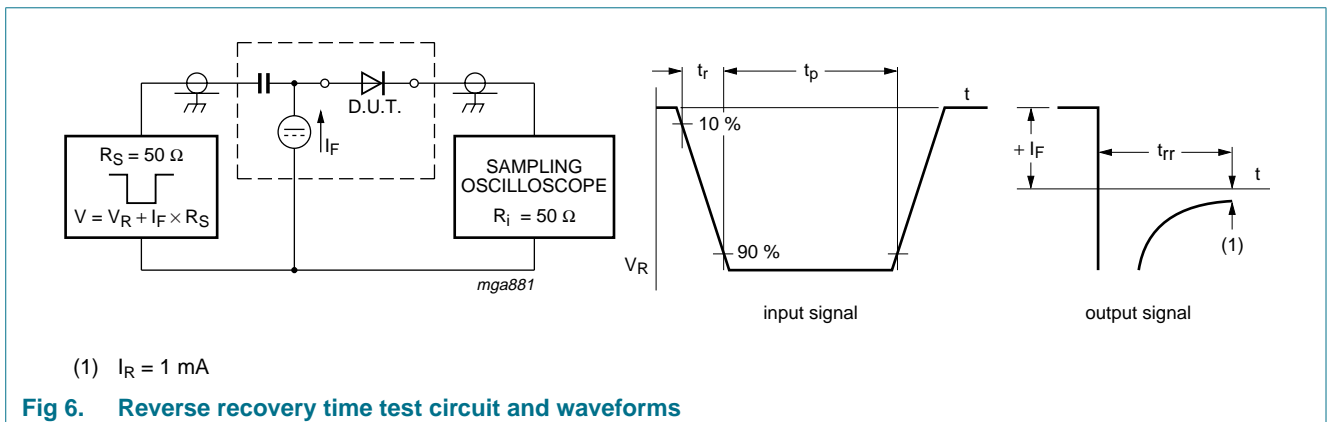


$f = 1\text{ MHz}$; $T_{amb} = 25\text{ }^\circ\text{C}$

Fig 4. Diode capacitance as a function of reverse voltage; typical values



8. Test information



11. Soldering

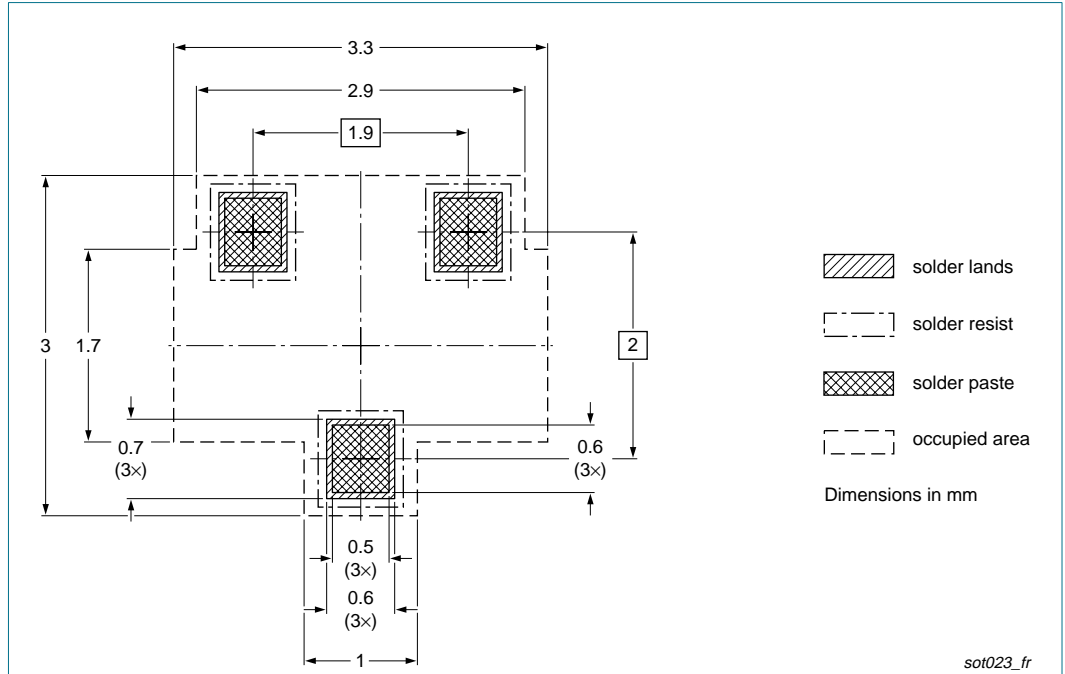


Fig 9. Reflow soldering footprint SOT23 (TO-236AB)

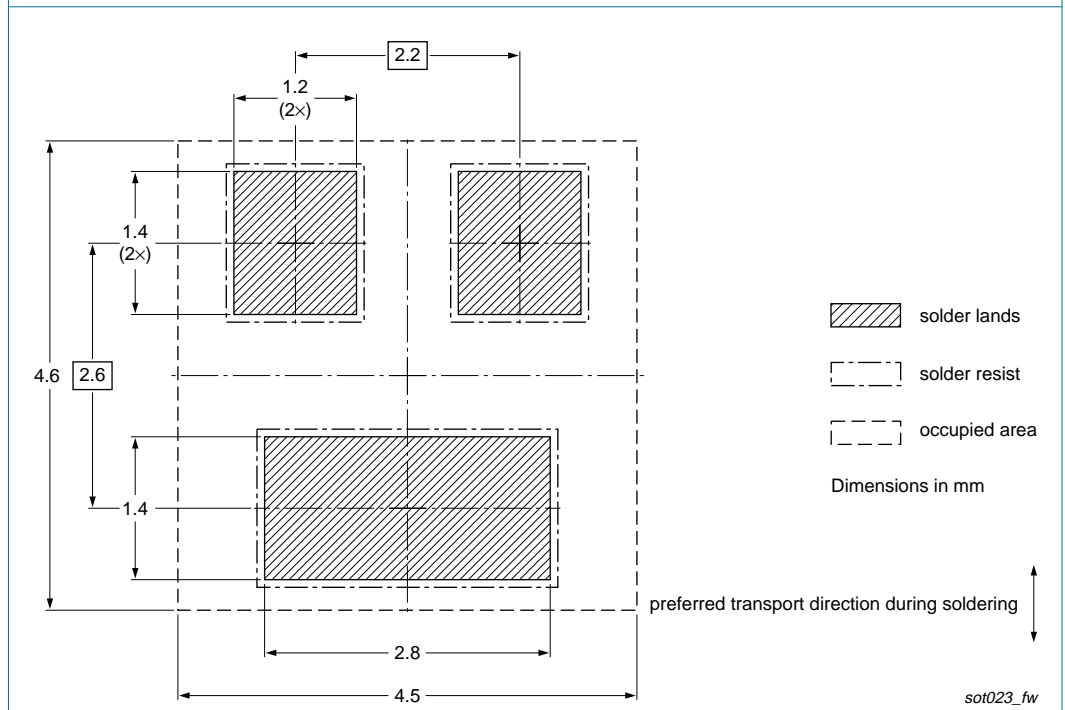


Fig 10. Wave soldering footprint SOT23 (TO-236AB)

12. Revision history

Table 10. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|----------------|--|-----------------------|---------------|------------|
| PMBD914_6 | 20090211 | Product data sheet | - | PMBD914_5 |
| Modifications: | <ul style="list-style-type: none">Type number PMBD914/DG addedSection 13 "Legal information": updated | | | |
| PMBD914_5 | 20071126 | Product data sheet | - | PMBD914_4 |
| PMBD914_4 | 20040106 | Product specification | - | PMBD914_3 |
| PMBD914_3 | 19990511 | Product specification | - | PMBD914_2 |
| PMBD914_2 | 19960918 | Product specification | - | PMBD914_1 |
| PMBD914_1 | 19960404 | Product specification | - | - |

13. Legal information

13.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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